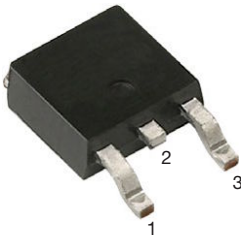
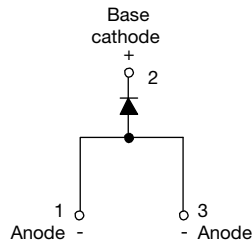


# High Voltage Surface Mountable Input Rectifier Diode, 8 A



DPAK (TO-252AA)



## FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Flexible solution for reliable AC power rectification
- High surge, low  $V_F$  rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
 COMPLIANT  
 HALOGEN  
**FREE**

## APPLICATIONS

- On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

## DESCRIPTION

The VS-8EWS12SLHM3 rectifier high voltage series has been optimized for very low forward voltage drop, with moderate leakage.

The **high reverse voltage** range available allows design of input stage primary rectification with **outstanding voltage surge** capability.

## PRIMARY CHARACTERISTICS

|                       |                 |
|-----------------------|-----------------|
| $I_{F(AV)}$           | 8 A             |
| $V_R$                 | 1200 V          |
| $V_F$ at $I_F$        | 1.1 V           |
| $I_{FSM}$             | 150 A           |
| $T_J$ max.            | 150 °C          |
| Package               | DPAK (TO-252AA) |
| Circuit configuration | Single          |

## OUTPUT CURRENT IN TYPICAL APPLICATIONS

| APPLICATIONS  | SINGLE-PHASE BRIDGE | THREE-PHASE BRIDGE | UNITS |
|---|---------------------|--------------------|-------|
| NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 $\mu$ m) copper | 1.2                 | 1.6                | A     |
| Aluminum IMS, $R_{thCA} = 15$ °C/W  | 2.5                 | 2.8                |       |
| Aluminum IMS with heatsink, $R_{thCA} = 5$ °C/W                           | 5.5                 | 6.5                |       |

### Note

- $T_A = 55$  °C,  $T_J = 125$  °C, footprint 300 mm<sup>2</sup>

## MAJOR RATINGS AND CHARACTERISTICS

| SYMBOL      | CHARACTERISTICS     | VALUES      | UNITS |
|-------------|---------------------|-------------|-------|
| $I_{F(AV)}$ | Sinusoidal waveform | 8           | A     |
| $V_{RRM}$   |                     | 1200        | V     |
| $I_{FSM}$   |                     | 150         | A     |
| $V_F$       | 8 A, $T_J = 25$ °C  | 1.10        | V     |
| $T_J$       |                     | -55 to +150 | °C    |

## VOLTAGE RATINGS

| PART NUMBER    | $V_{RRM}$ , MAXIMUM PEAK REVERSE VOLTAGE<br>V | $V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE<br>V | $I_{RRM}$ AT 150 °C<br>mA |
|----------------|---|--|---------------------------|
| VS-8EWS12SLHM3 | 1200  | 1300   | 0.50                      |



| ABSOLUTE MAXIMUM RATINGS                            |               |  |        |                             |
|---|---------------|--|--------|-----------------------------|
| PARAMETER   | SYMBOL        | TEST CONDITIONS  | VALUES | UNITS                       |
| Maximum average forward current                     | $I_{F(AV)}$   | $T_C = 105\text{ }^\circ\text{C}$ , 180° conduction half sine wave | 8      | A                           |
| Maximum peak one cycle non-repetitive surge current | $I_{FSM}$     | 10 ms sine pulse, rated $V_{RRM}$ applied                          | 125    |                             |
|   |               | 10 ms sine pulse, no voltage reapplied                             | 150    |                             |
| Maximum $I^2t$ for fusing                           | $I^2t$        | 10 ms sine pulse, rated $V_{RRM}$ applied                          | 78     | $\text{A}^2\text{s}$        |
|   |               | 10 ms sine pulse, no voltage reapplied                             | 110    |                             |
| Maximum $I^2\sqrt{t}$ for fusing                    | $I^2\sqrt{t}$ | $t = 0.1\text{ ms to }10\text{ ms}$ , no voltage reapplied         | 1100   | $\text{A}^2\sqrt{\text{s}}$ |

| ELECTRICAL SPECIFICATIONS       |             |                                       |        |                  |
|---------------------------------|-------------|---------------------------------------|--------|------------------|
| PARAMETER                       | SYMBOL      | TEST CONDITIONS                       | VALUES | UNITS            |
| Maximum forward voltage drop    | $V_{FM}$    | 8 A, $T_J = 25\text{ }^\circ\text{C}$ | 1.1    | V                |
| Forward slope resistance        | $r_t$       | $T_J = 150\text{ }^\circ\text{C}$     | 20     | $\text{m}\Omega$ |
| Threshold voltage               | $V_{F(TO)}$ |                                       | 0.82   | V                |
| Maximum reverse leakage current | $I_{RM}$    | $T_J = 25\text{ }^\circ\text{C}$      | 0.05   | mA               |
|                                 |             | $T_J = 150\text{ }^\circ\text{C}$     | 0.50   |                  |

| THERMAL - MECHANICAL SPECIFICATIONS                         |                  |                            |             |                           |
|---|------------------|----------------------------|-------------|---------------------------|
| PARAMETER   | SYMBOL           | TEST CONDITIONS            | VALUES      | UNITS                     |
| Maximum junction and storage temperature range              | $T_J, T_{Stg}$   |                            | -55 to +150 | $^\circ\text{C}$          |
| Maximum thermal resistance, junction to case                | $R_{thJC}$       | DC operation               | 2.5         | $^\circ\text{C}/\text{W}$ |
| Typical thermal resistance, junction to ambient (PCB mount) | $R_{thJA}^{(1)}$ |                            | 62          |                           |
| Approximate weight  |                  |                            | 1           | g                         |
|   |                  |                            | 0.03        | oz.                       |
| Marking device  |                  | Case style DPAK (TO-252AA) | 8EWS12SH    |                           |

**Note**

(1) When mounted on 1" square (650 mm<sup>2</sup>) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40  $^\circ\text{C}/\text{W}$

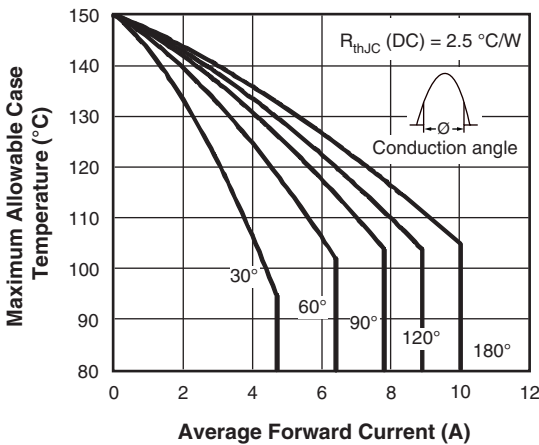


Fig. 1 - Current Rating Characteristics

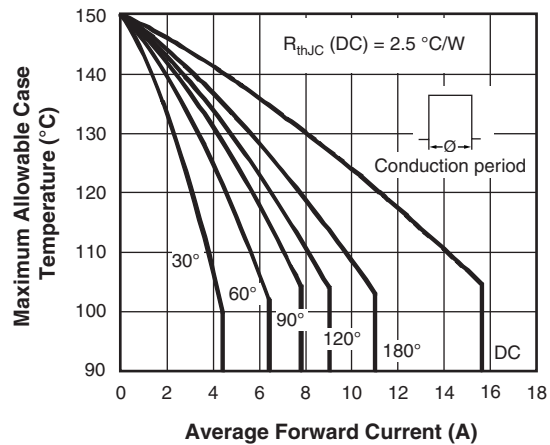


Fig. 2 - Current Rating Characteristics

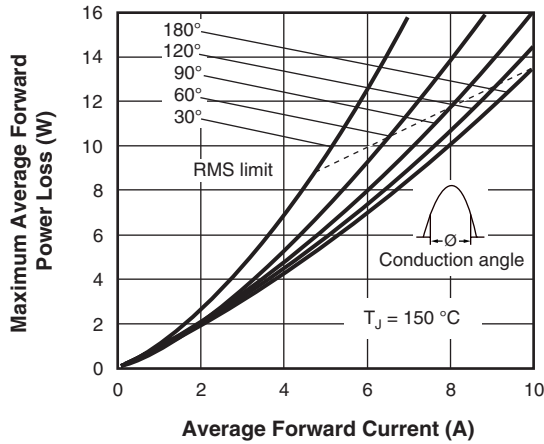


Fig. 3 - Forward Power Loss Characteristics

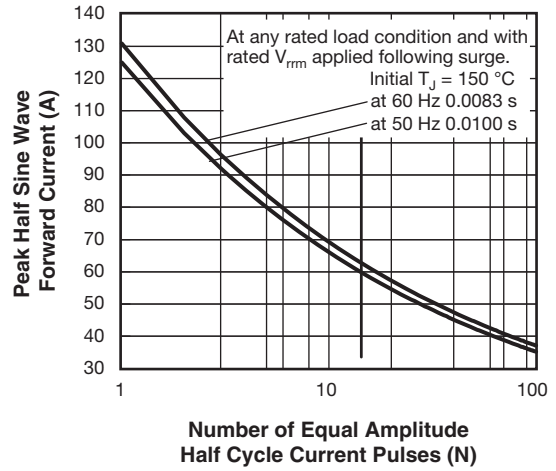


Fig. 5 - Maximum Non-Repetitive Surge Current

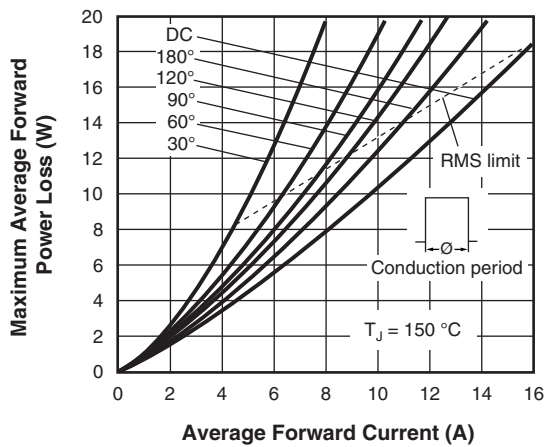


Fig. 4 - Forward Power Loss Characteristics

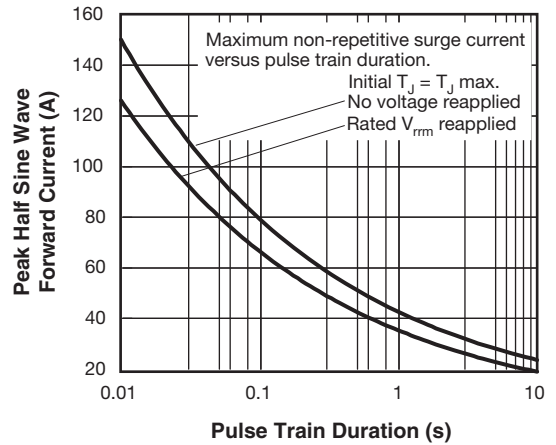


Fig. 6 - Maximum Non-Repetitive Surge Current

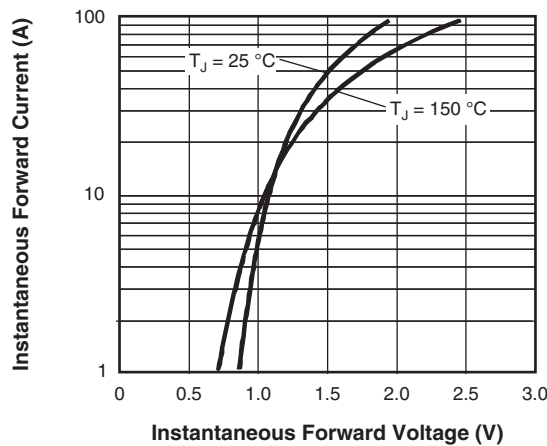
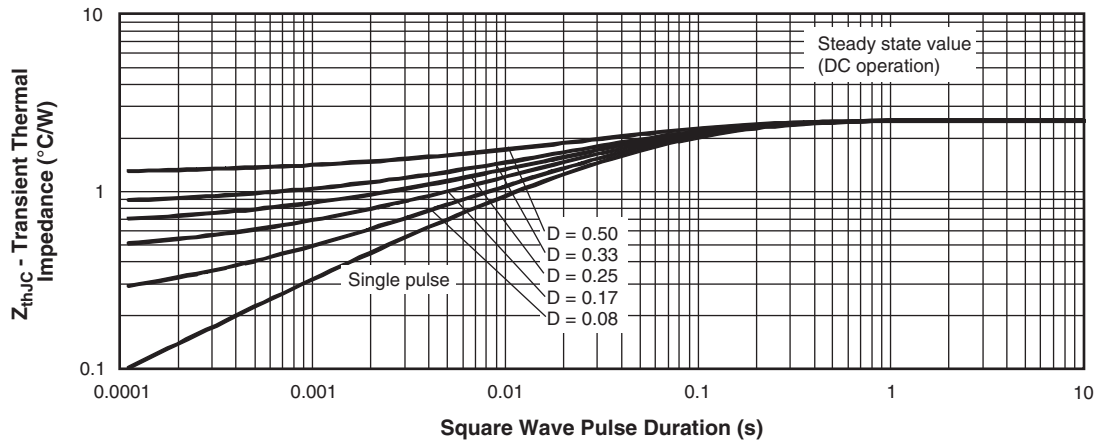


Fig. 7 - Forward Voltage Drop Characteristics


 Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

**ORDERING INFORMATION TABLE**

|             |            |          |          |          |          |           |          |          |          |           |
|-------------|------------|----------|----------|----------|----------|-----------|----------|----------|----------|-----------|
| Device code | <b>VS-</b> | <b>8</b> | <b>E</b> | <b>W</b> | <b>S</b> | <b>12</b> | <b>S</b> | <b>L</b> | <b>H</b> | <b>M3</b> |
|             | ①          | ②        | ③        | ④        | ⑤        | ⑥         | ⑦        | ⑧        | ⑨        | ⑩         |

- ① - Vishay Semiconductors product
- ② - Current rating (8 = 8 A)
- ③ - Circuit configuration:  
E = single
- ④ - Package:  
W = DPAK (TO-252AA)
- ⑤ - Type of silicon:  
S = standard recovery rectifier
- ⑥ - Voltage code x 100 =  $V_{RRM}$  — 12 = 1200 V
- ⑦ - S = surface mountable
- ⑧ - L = tape and reel (left oriented), for different orientation contact factory
- ⑨ - H = AEC-Q101 qualified
- ⑩ - Environmental digit:  
M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

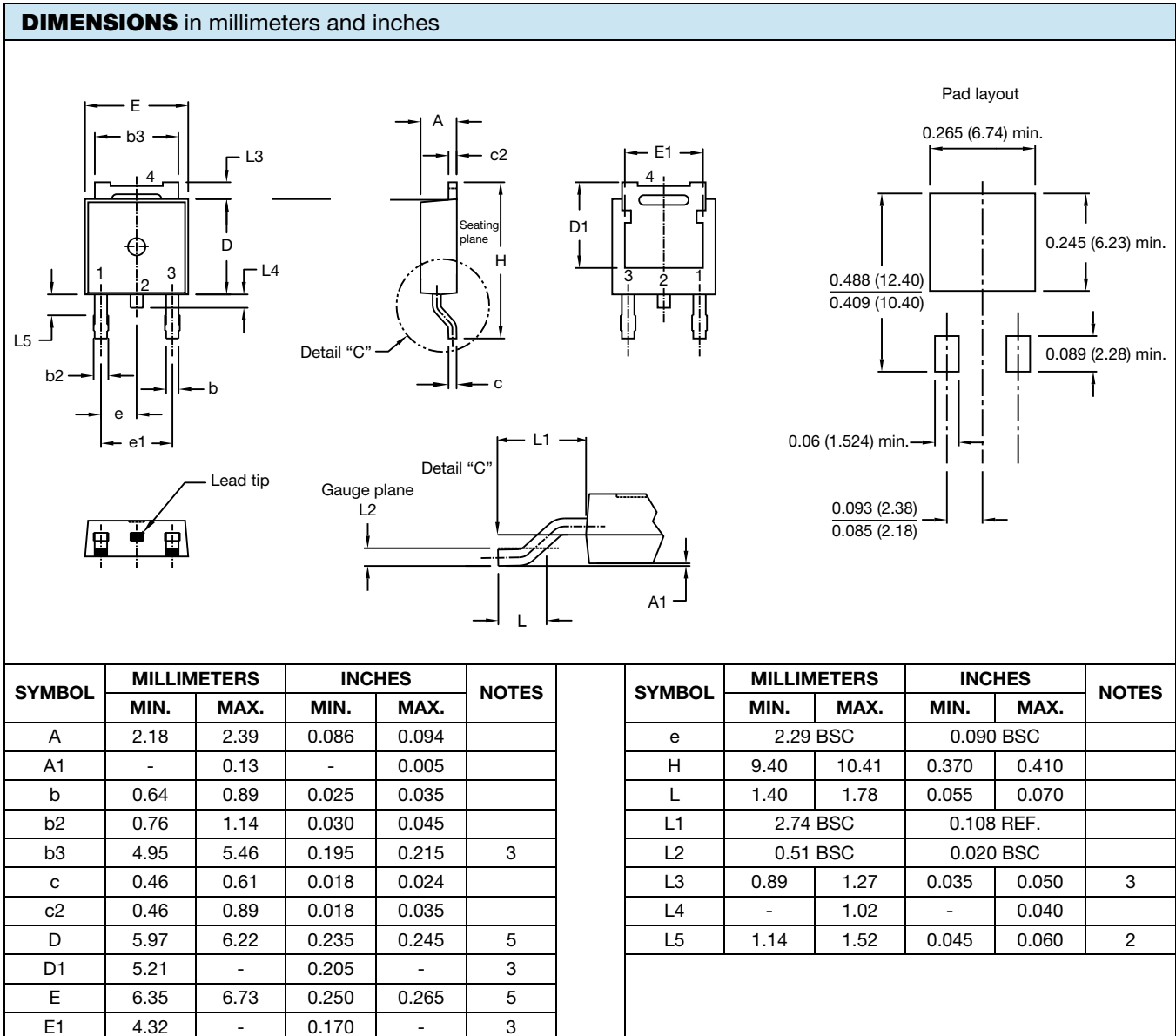
**ORDERING INFORMATION (Example)**

| PREFERRED P/N  | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION |
|----------------|------------------|------------------------|-----------------------|
| VS-8EWS12SLHM3 | 3000             | 3000                   | 13" diameter reel     |

**LINKS TO RELATED DOCUMENTS**

|                          |  |
|--------------------------|--|
| Dimensions               | <a href="http://www.vishay.com/doc?95519">www.vishay.com/doc?95519</a> |
| Part marking information | <a href="http://www.vishay.com/doc?95518">www.vishay.com/doc?95518</a> |
| Packaging information    | <a href="http://www.vishay.com/doc?96495">www.vishay.com/doc?96495</a> |
| SPIICE model             | <a href="http://www.vishay.com/doc?96668">www.vishay.com/doc?96668</a> |

### DPAK (TO-252AA)



**Notes**

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (5) Outline conforms to JEDEC® outline TO-252AA



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